

PRM012N10CT

PFC Device Corporation

100V Single N-Channel MOSFET

Major ratings and characteristics

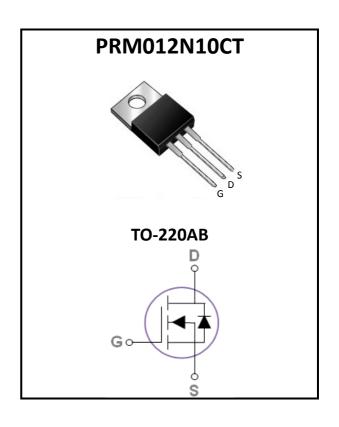
Characteristics	Values	Units
V _{DS}	100	V
I _D (Τ _C =25°C)	58	Α
Max. R _{DS(ON)} @V _{GS} =10V	12	mΩ
Max. $R_{DS(ON)}@V_{GS}=4.5V$	15	mΩ
T _J Operating Junction Temperature	-55 to +150	°C

General Description

The N-Channel enhancement mode power field effect transistor is using trench DMOS technology. This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. The device is well suited for high efficiency fast switching applications.

Typical Applications

- Charger Adapter
- Power Tools
- LED Lighting



Features

- Max. $R_{DS(ON)}=12m\Omega@V_{GS}=10V$
- Improved dv/dt capability
- Fast switching
- 100% E_{AS} Guaranteed
- Green Device Available

1. Characteristics

Maximum Ratings Characteristics

($T_A = 25$ °C unless otherwise specified)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	100	V
V_{GS}	Gate-Source Voltage	±20	V
I	Drain Current – Continuous (T _C =25°C)	58	А
I _D	Drain Current – Continuous (T _C =100°C)	36.6	А
I _{DM}	Drain Current – Pulsed ¹	180	А
E _{AS}	Single Pulse Avalanche Energy ²	58	mJ
I _{AS}	Single Pulse Avalanche Current ²	17	А
Р	Power Dissipation (T _C =25°C)	83.3	W
P _D	Power Dissipation – Derate above 25°C	0.66	W/°C
T _{STG}	Storage Temperature Range	-55 to 150	°C
Τ _J	Operating Junction Temperature Range	-55 to 150	°C

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{ extsf{ heta}JA}$	Thermal Resistance Junction to ambient		62	°C/W
$R_{ extsf{ heta}JC}$	Thermal Resistance Junction to Case		1.5	°C/W



Electrical Characteristics

($T_J = 25$ °C unless otherwise specified)

Off Characteristics

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BV_{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250uA	100			V
	Drain Courses Lookense Current	V _{DS} =100V, V _{GS} =0V, T _J =25°C			1	uA
IDSS	Drain-Source Leakage Current	V _{DS} =100V, V _{GS} =0V, T _J =125°C			250	uA
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V, V _{DS} =0V			±100	nA

On Characteristics

R _{DS(ON)} Static Drain-Source On-Resistance	V _{GS} =10V, I _D =20A			12	mΩ	
R _{DS(ON)}	Static Drain-Source On-Resistance	V _{GS} =4.5V, I _D =10A			15	mΩ
V _{GS(th)}	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =250uA	1.0		2.5	V
g _{fs}	Forward Transconductance	V _{DS} =5V, I _D =20A		55		S

Dynamic and switching Characteristics

Qq	Total Gate Charge		 37	
Q _{gs}	Gate-Source Charge	V_{DS} =50V, V_{GS} =10V, I_{D} =20A	 7	 nC
Q _{ad}	Gate-Drain Charge		 7	
T _{d(on)}	Turn-On Delay Time		 11	
T _r	Turn-On Rise Time	V_{DD} =50V, V_{GS} =10V, R_{G} =6 Ω I_{D} =20A	 42	 20
T _{d(off)}	Turn-Off Delay Time		 41	 ns
T _f	Turn-Off Fall Time		 80	
C _{iss}	Input Capacitance		 2200	
C _{oss}	Output Capacitance	V _{DS} =50V, V _{GS} =0V, f=1MHz	 210	 pF
C _{rss}	Reverse Transfer Capacitance		 30	
R _q	Gate resistance	V _{GS} =0V, V _{DS} =0V, f=1MHz	 1.6	 Ω

Drain-Source Diode Characteristics

V _{SD} ³	Source to Drain Diode Voltage	V _{GS} =0V, I _S =20A	 	1.5	V
t _{rr}	Reverse Recovery Time	L 204 di/dt 1004/up	 45		ns
Q _{rr}	Reverse Recovery Charge	I _S =20A, di/dt=100A/us	 51		nC

Note :

1. Repetitive Rating : Pulsed width limited by maximum junction temperature.

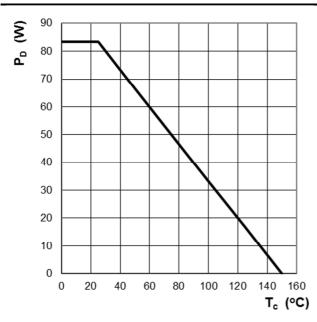
2. VDD=50V, VGS=10V, L=0.4mH, IAS=17A, RG=25Ω, Starting TJ=25°C

3. The data tested by pulsed, pulse width \leq 300us, duty cycle \leq 2%.





Ratings and Characteristics Curves





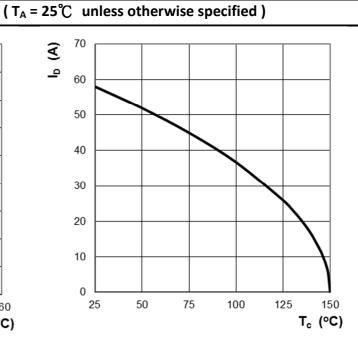
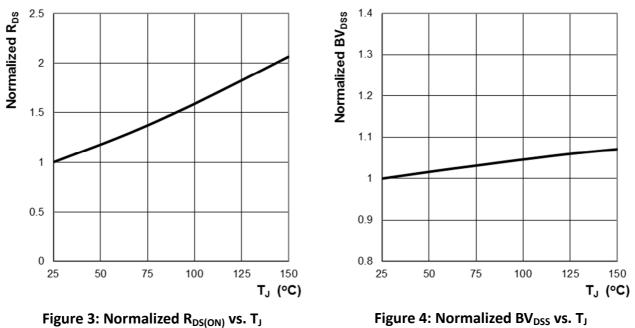
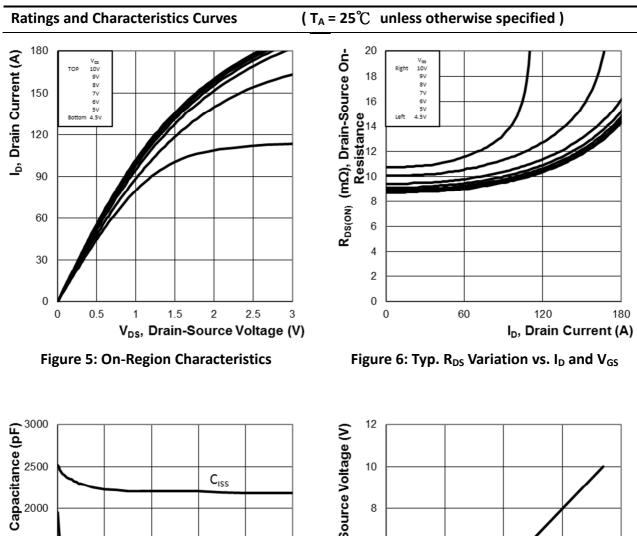


Figure 2: Continuous Drain Current vs. T_c









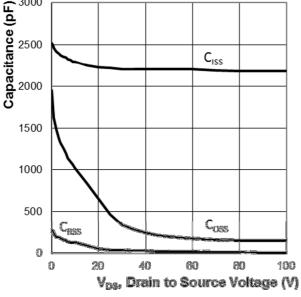


Figure 7: Typ. Capacitance Characteristics

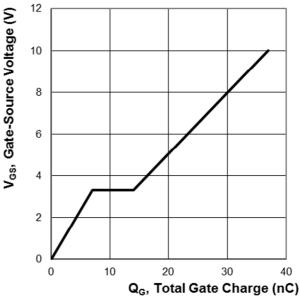
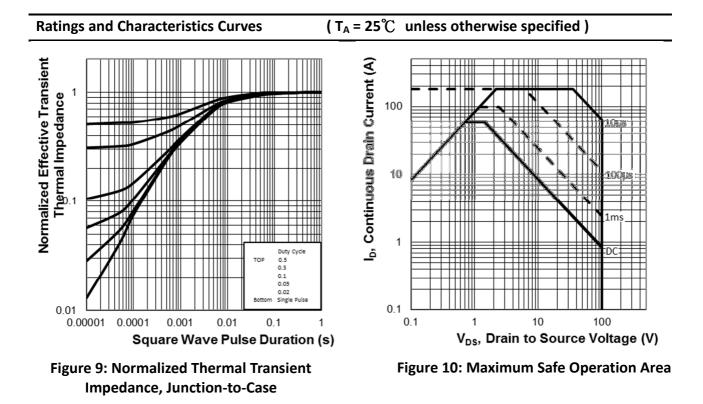


Figure 8: Typ. Gate Charge Characteristics

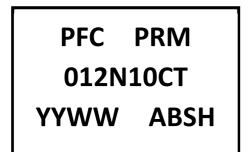






3. Marking information

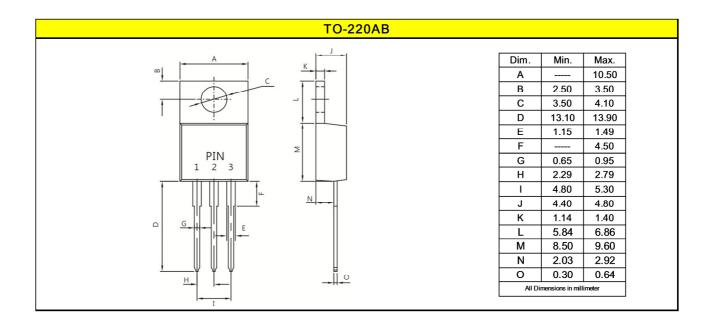
Top Marking Rule



PRM012N10CT = Product Type Marking Code YYWW = Date Code YY = Last two digits of year WW = Week code ABS = Assembly code H = Halogen Free (N/A = common molding compound)

4. Package information

Package Outline Dimensions millimeters





5. Ordering information

Part Number	Package	Delivery mode
PRM012N10CT	TO-220AB	50 pcs / Tube

Mechanical

- Molder Plastic: UL Flammability Classification Rating 94V-0
- Device Weight : 0.07 ounces (1.96grams) TO-220ÅB
- Mounting Torque : Recommended 4~5 kg-cm

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